

BCT2040 1A Low Dropout Linear Regulators

GENERAL DESCRIPTION

The BCT2040 series low-power, low-noise, low-dropout, CMOS linear voltage regulators operate from a 2.2V to 6.0V input voltage. They are the perfect choice for low voltage, low power applications. A low ground current makes this part attractive for battery operated power systems. The BCT2040 series also offer ultra-low dropout voltage to prolong battery life in portable electronics. Output current minimum limit is 1A, and over-current protection limit is set at 2A typical.

These devices feature a shutdown function and are offered in active low with auto discharge. The output voltage is preset to voltages in the range of 1.0V to 5.0V. Other features include a low shutdown current, fold-back current limit and thermal shutdown protection.

The BCT2040 is available in Green ESOP-8 packages. It operates over an ambient temperature range of -40°C to +85°C.

FEATURES

- Wide Input Voltage Range: 2.2V to 6.0V
- Fixed Outputs of1.0V, 1.2V, 1.5V, 1.8V, 2.5V, 2.8V, 3.0V 3.3V and 5.0V
- Adjustable Output from 0.8V to 5.0V
- 1A Current Rating
- Low Dropout Voltage
- Output Current Limit
- Quick output discharge
- Thermal-Overload Protection
- High PSRR(65dB at 1kHz)
- -40°C to 85°C Operating Temperature Range
- Available in Green ESOP-8 Packages

APPLICATIONS

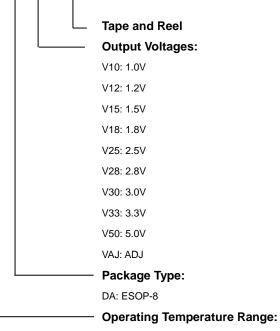
Cellular Telephones Cordless Telephones PCMCIA Cards Modems MP3 Player Hand-Held Instruments Portable/Battery-Powered Equipment



ORDERING INFORMATION

Order Number	V _{OUT} (V)	Package Type	Temperature Range	Marking	QTY/Reel	
BCT2040EDAV10-TR	1.0	ESOP-8	-40°C to +85°C	2040 10XXX	3000	
BCT2040EDAV12-TR	1.2	ESOP-8	-40°C to +85°C	2040 12XXX	3000	
BCT2040EDAV15-TR	1.5	ESOP-8	-40°C to +85°C	2040 15XXX	3000	
BCT2040EDAV18-TR	1.8	ESOP-8	-40°C to +85°C	2040 18XXX	3000	
BCT2040EDAV25-TR	2.5	ESOP-8	-40°C to +85°C	2040 25XXX	3000	
BCT2040EDAV28-TR	2.8	ESOP-8	-40°C to +85°C	2040 28XXX	3000	
BCT2040EDAV30-TR	3.0	ESOP-8	-40°C to +85°C	2040 30XXX	3000	
BCT2040EDAV33-TR	3.3	ESOP-8	-40°C to +85°C	2040 33XXX	3000	
BCT2040EDAV50-TR	5.0	ESOP-8	-40°C to +85°C	2040 50XXX	3000	
BCT2040EDAVAJ-TR	ADJ	ESOP-8	-40°C to +85°C	2040 AJXXX	3000	

ORDER NUMBER BCT2040 <u>X XX VXX</u> -TR



E: -40℃ to +85℃

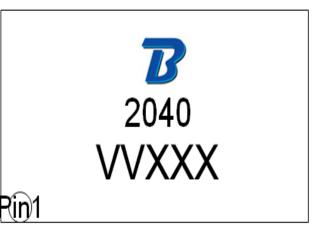


MARKING DESCRIPTION

2040: Part No.

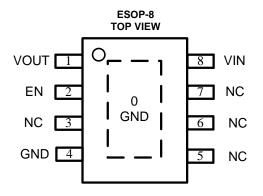
VV: Output Voltage Code

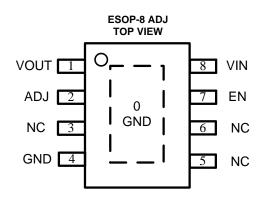
Code	V _{OUT} (V)
10	1.0
12	1.2
15	1.5
18	1.8
25	2.5
28	2.8
30	3.0
33	3.3
50	5.0
AJ	ADJ



XXX: Batch code

PIN CONFIGURATION







PIN DESCRIPTION

PIN			FUNCTION	
Vxx	ADJ	NAME	FUNCTION	
1	1	VOUT	Regulator Output.	
2		EN	Enable pin, active high.	
	2	ADJ	Output voltage adjust pin.	
3	3	NC	Not connected.	
4	4	GND	Ground	
5	5	NC	Not connected.	
6	6	NC	Not connected.	
7		NC	Not connected.	
	7	EN	Enable pin, active high.	
8	8	VIN	Regulator Input.	
0	0	GND	Ground, Thermal pin.	

ABSOLUTE MAXIMUM RATINGS

IN to GND0.3V to 6.5V
EN to GND0.3V to V_{IN}
OUT to GND0.3V to (V_{IN}+0.3V)
Output Short-Circuit DurationInfinite
Power Dissipation, $P_D@T_A=25\degree$ C ESOP-81.25W
Package Thermal Resistance ESOP-8, θ_{JA} 100°C/W
Junction Temperature150°C
Operating Temperature Range40 $^\circ\!\!\mathbb{C}$ to +85 $^\circ\!\!\mathbb{C}$
Storage Temperature Range65 $^\circ\!\!\!\!\!^\circ$ to 150 $^\circ\!\!\!\!^\circ\!\!\!\!^\circ$
Lead Temperature (Soldering, 10 sec)260 $^\circ\!\!\mathbb{C}$
ESD Susceptibility HBM4000V

NOTE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. Broadchip recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

Broadchip reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time. Please contact Broadchip sales office to get the latest datasheet.



ELECTRICAL CHARACTERISTICS

PARAMETER	SYM	CONDITIONS		MIN	TYP	MAX	UNITS
Input Voltage	V _{IN}			2.2		6.0	V
Output Voltage Accuracy ⁽¹⁾		I _{OUT} =1mA		-2.0		2.0	%
FB Reference Voltage, ADJ pin	V _{REF}	I _{OUT} =1mA		0.78	0.8	0.82	V
Maximum Output Current ⁽¹⁾		V _{IN} =2.2V or (V _{OUT} +0.5	V)	1			Α
Current Limit ⁽¹⁾	I _{LIM}	V _{IN} =2.2V or (V _{OUT} +0.5	V)		1.8		Α
Short-Circuit Current ⁽¹⁾	I _{SHORT}	V _{IN} =2.2V or (V _{OUT} +0.5	V)		0.6		Α
Ground Pin Current	Ι _Q	No load, EN=2V			30		uA
Dropout Voltage ⁽²⁾		V _{OUT} >2.2V, I _{OUT} =300mA			0.1	0.2	- V
Dropout Voltage		V _{OUT} >2.2V, I _{OUT} =1A			0.3	0.5	
Line Regulation ⁽¹⁾	A 1/	V _{IN} =2.2V or (V _{OUT} +0.5V) to 6V,			0.05		%/V
	ΔV_{LNR}	I _{OUT} =1mA			0.05		70/ V
		I _{OUT} =1mA to 1A, C _{OUT} =	C _{OUT} =4.7uF,		0.002		– %/mA
Load Regulation	ΔV_{LDR}	V _{OUT} >2V					
Load Regulation		I _{OUT} =1mA to 1A, C _{OUT} =4.7uF,			0.004		
		V _{OUT} ≪2V			0.004		
	PSRR	C _{BP} =0.1uF,	f=		65		– dB
Power Supply Rejection Ratio		I _{LOAD} =50mA, C _{OUT} =4.7uF,	217Hz		00		
					60		u.D
		V _{IN} =V _{OUT} +1V	f=1kHz		00		
SHUTDWON ⁽³⁾		1					
EN Input Threshold	VIH	V _{IN} =2.2V to 6.0V, V _{EN} =-0.3V to V _{IN}		1.5			v
	V _{IL}					0.3	v
EN Input Bias Current	L.	EN=6.0V			1.5		uA
EN liiput bias Current	I _{IN}	EN=0V			0.01		uA
Shutdown Supply Current	I _{Q(SHDN)}	EN=0.4V			0.01	1	uA
Shutdown Exit Delay ⁽⁴⁾		C _{OUT} =4.7uF, No Load			30		us
THERMAL PROTECTION					·		·
Thermal Shutdown Temperature	T _{SHDN}	N			150		°C
Thermal Shutdown Hysteresis					15		°C

NOTES:

1. VIN = VOUT (NOMINAL) + 0.5V or 2.5V, whichever is greater.

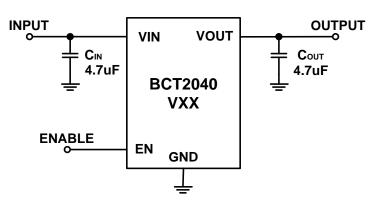
2. The dropout voltage is defined as VIN - VOUT, when VOUT is 100mV below the value of nominal VOUT. (Only applicable for VOUT > +2.2V.)

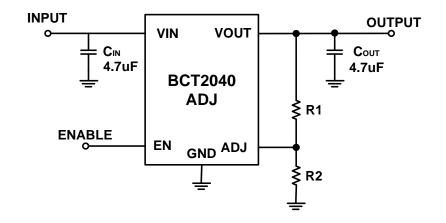
3. VEN = -0.3V to VIN

4. Time needed for VOUT to reach 90% of final value.



TYPICAL APPLICATION CIRCUIT





NOTE: VOUT = (R1 + R2)/ R2 × 0.8 V



APPLICATION NOTE

Programming the BCT2040 Adjustable LDO regulator

The output voltage of the BCT2040 adjustable regulator is programmed using an external resistor divider as show in Figure as below. The output voltage is calculated using equation as below:

$$V_{OUT} = V_{REF} \times \left(1 + \frac{R1}{R2}\right)$$

Where:

V_{REF}=0.8V typ (the internal reference voltage)

Resistors R1 and R2 should be chosen for approximately 50uA divider current. Lower value resistors can be used for improved noise performance, but the solution consumes more power. Higher resistor values should be avoided as leakage current into/out of FB across R1/R2 creates an offset voltage that artificially increases/decreases the feedback voltage and thus erroneously decrease/increases V_{OUT}.

Enable Function

The BCT2040 features an LDO regulator enable/disable function. To assure the LDO regulator will switch on; the EN turn on control level must be greater than 1.5 volts. The LDO regulator will go into the shutdown mode when the voltage on the EN pin falls below 0.3 volts. For to protect the system, the BCT2040 have a quick discharge function. If the enable function is not needed in a specific application, it may be tied to VIN to keep the LDO regulator in a continuously on state.

Thermal Considerations

Thermal protection limits power dissipation in BCT2040. When the operation junction temperature exceeds 150°C, the OTP circuit starts the thermal shutdown function turn the pass element off. The pass element turns on again after the junction temperature cools by 15°C.

For continue operation, do not exceed absolute maximum operation junction temperature 150°C. The power dissipation definition in device is:

 $\mathsf{P}_\mathsf{D} = (\mathsf{V}_\mathsf{IN} \text{-} \mathsf{V}_\mathsf{OUT}) \times \mathsf{I}_\mathsf{OUT} + \mathsf{V}_\mathsf{IN} \times \mathsf{I}_\mathsf{Q}$

The maximum power dissipation depends on the thermal resistance of IC package, PCB layout, the rate of surroundings airflow and temperature difference between junction to ambient. The maximum power dissipation can be calculated by following formula:

 $\mathsf{P}_\mathsf{D}(\mathsf{MAX}) = (\mathsf{T}_\mathsf{J}(\mathsf{MAX}) - \mathsf{T}_\mathsf{A}) / \theta_\mathsf{JA}$



Where $T_J(MAX)$ is the maximum operation junction temperature 150°C, T_A is the ambient temperature and the θ_{JA} is the junction to ambient thermal resistance. For recommended operating conditions specification of BCT2040, where $T_J(MAX)$ is the maximum junction temperature of the die (150°C) and T_A is the maximum ambient temperature. The junction to ambient thermal resistance (θ_{JA} is layout dependent) for ESOP-8 package is 100°C/W, on standard JEDEC 51-3 thermal test board. The maximum power dissipation at $T_A = 25$ °C can be calculated by following formula:

 $P_D(MAX) = (150^{\circ}C-25^{\circ}C)/100 = 1.25W (ESOP-8)$

The maximum power dissipation depends on operating ambient temperature for fixed T_J(MAX) and thermal resistance θ_{JA} . It is also useful to calculate the junction of temperature of the BCT2040 under a set of specific conditions. In this example let the Input voltage V_{IN}=3.3V, the output current Io=500mA and the case temperature T_A=40°C measured by a thermal couple during operation. The power dissipation for the Vo=2.8V version of the BCT2040 can be calculated as:

P_D = (3.3V-2.8V) ×500mA+3.3V×100uA =250.33mW

And the junction temperature, T_J, can be calculated as follows:

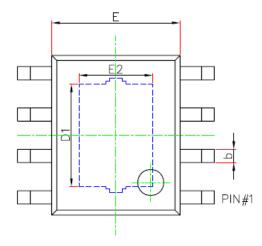
 $T_J = T_A + P_D \times \theta_{JA} = 40^{\circ}C + 0.25W \times 100^{\circ}C/W$ =40°C+25°C=65°C<T_J(MAX) =150°C

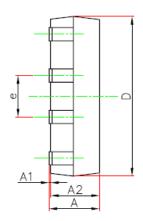
For this operating condition, T_J is lower than the absolute maximum operating junction temperature,150°C, so it is safe to use the BCT2040 in this configuration.

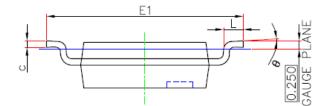


PACKAGE OUTLINE DIMENSIONS

ESOP-8

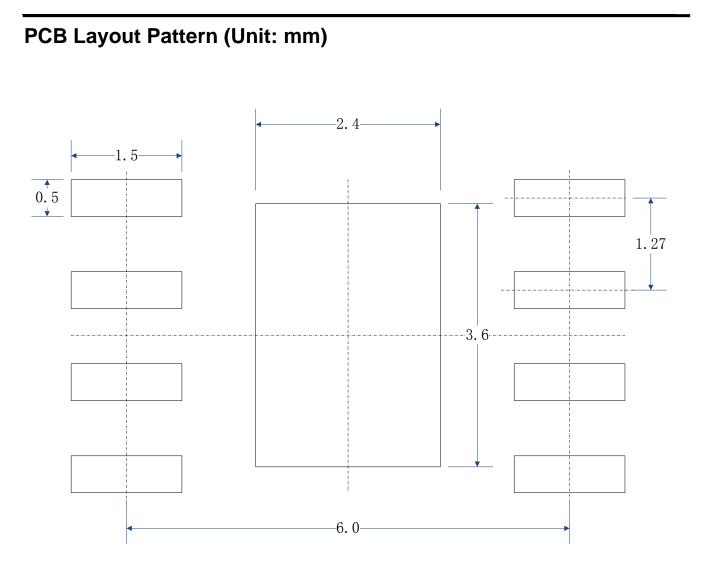






Symbol	Dimensions In	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	1.300	1.700	0.051	0.067	
A1	0.000	0.100	0.000	0.004	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.007	0.010	
D	4.700	5.100	0.185	0.201	
D1	3.050	3.250	0.120	0.128	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
E2	2.160	2.360	0.085	0.093	
е	1.270(BSC)		0.050(BSC)		
L	0.400	1.270	0.016	0.050	
θ	0 °	8°	0°	8°	





X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Linear Voltage Regulators category:

Click to view products by BROADCHIP manufacturer:

Other Similar products are found below :

LV56831P-E LV5684PVD-XH MCDTSA6-2R L7815ACV-DG PQ3DZ53U LV56801P-E TLE42794G L78L05CZ/1SX L78LR05DL-MA-E 636416C 714954EB BA033LBSG2-TR LV5680P-E L78M15CV-DG TLS202B1MBV33HTSA1 L79M05T-E TLS202A1MBVHTSA1 L78LR05D-MA-E NCV317MBTG NTE7227 LV5680NPVC-XH LT1054CN8 MP2018GZD-5-Z MP2018GZD-33-Z MIC5281-3.3YMM MC78L06BP-AP TA48LS05F(TE85L,F) TA78L12F(TE12L,F) TC47BR5003ECT TCR2LN12,LF(S TCR2LN28,LF(S TCR2LN30,LF(S TCR3DF295,LM(CT TCR3DF40,LM(CT BA178M20CP-E2 L78M12ABDT LM7812SX/NOPB LR645N3-G-P003 LR645N3-G-P013 ZXTR2005P5-13 SCD7812BTG TCR3DF335,LM(CT ZXTR2012K-13 TLE42994E V33 ZXTR2008K-13 ZXTR2005K-13 L88R05DL-E ADP3300ARTZ-2.7RL7 LM120K-15/883 IFX54441LDVXUMA1